

Features

- Wide supply voltage range from 0.9V to 3.6V
- Inputs accept voltages up to 3.6V
- I_{OFF} supports partial-power-down mode
- Low static power consumption; I_{CC}=0.5μA (Max.)
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

General Description

The is a single bus buffer/line driver with 3-state output. When the output enable (OE) is high the output will be disabled. In contrast, when the OE is low, true data will pass from A input to the Y output.

Applications

- AV Receiver
- Audio Dock: Portable
- Blu-ray Player and Home Theater
- Embedded PC
- Personal Digital Assistant(PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drive(SSD): Client and Enterprise
- Wireless Headset, Keyboard, and Mouse

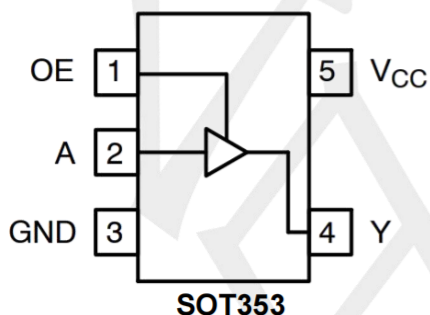
Logic Diagram



Ordering Information

ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION
NC7SV126P5X-TP	SOT353	Tape and Reel, 3000

Pin Configuratio (TOP VIEW)



Function Table (each gate)

Input		Output
OE	A	Y
H	L	L
H	H	H
L	X	Z

H: HIGH voltage level; L: LOW voltage level;

Absolute Maximum Ratings

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNIT
Supply Voltage	V _{CC}		-0.5 ~ +4.3	V
Input Voltage	V _{IN}		-0.5 ~ +4.3	V
Output Voltage	V _{OUT}	Output in the high or low state	-0.5 ~ +V _{CC} +0.5V	V
		Output in the power-off state	-0.5 ~ +4.3	V
VCC or GND Current	I _{CC}		±50	mA
Continuous Output Current	I _{OUT}	V _{OUT} =0~V _{CC}	±20	mA
Input Clamp Current	I _{IK}	V _{IN} <0	-50	mA
Output Clamp Current	I _{OK}	V _{OUT} <0	-50	mA
Storage Temperature Range	T _{STG}		-65 ~ +150	°C
Junction to Ambient	θ _{JA}	SOT353	280	°C/W

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V _{CC}	Operating	0.9	--	3.6	V
Input Voltage	V _{IN}		0	--	3.6	V
Output Voltage	V _{OUT}	High or low state	0	--	V _{CC}	V
Input Transition Rise or Fall Rate	Δt/Δv	V _{CC} =0.9V ~ 3.6V	--	--	200	ns/V
Operating Temperature	T _A		-40	--	+125	°C

Electrical Characteristics ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
High-level Input Voltage	V_{IH}	$V_{CC}=0.9\text{V}$	$0.7 \times V_{CC}$	--	--	V	
		$V_{CC}=0.9\text{V} \sim 1.95\text{V}$	$0.65 \times V_{CC}$	--	--	V	
		$V_{CC}=2.3\text{V} \sim 2.7\text{V}$	1.6	--	--	V	
		$V_{CC}=3\text{V} \sim 3.6\text{V}$	2	--	--	V	
Low-level Input Voltage	V_{IL}	$V_{CC}=0.9\text{V}$	--	--	$0.3 \times V_{CC}$	V	
		$V_{CC}=1.1\text{V} \sim 1.95\text{V}$	--	--	$0.35 \times V_{CC}$	V	
		$V_{CC}=2.3\text{V} \sim 2.7\text{V}$	--	--	0.7	V	
		$V_{CC}=3\text{V} \sim 3.6\text{V}$	--	--	0.9	V	
High-Level Output Voltage	V_{OH}	$V_{CC}=0.9 \sim 3.6\text{V}, I_{OH}=-20\mu\text{A}$	$V_{CC}-0.1$	--	--	V	
		$V_{CC}=1.1\text{V}, I_{OH}=-1.1\text{mA}$	$0.75 \times V_{CC}$	--	--	V	
		$V_{CC}=1.4\text{V}, I_{OH}=-1.7\text{mA}$	1.11	--	--	V	
		$V_{CC}=1.65\text{V}, I_{OH}=-1.9\text{mA}$	1.32	--	--	V	
		$V_{CC}=2.3\text{V}$	$I_{OH}=-2.3\text{mA}$	2.05	--	--	V
			$I_{OH}=-3.1\text{mA}$	1.9	--	--	V
		$V_{CC}=3\text{V}$	$I_{OH}=-2.7\text{mA}$	2.72	--	--	V
			$I_{OH}=-4\text{mA}$	2.6	--	--	V
Low-Level Output Voltage	V_{OL}	$V_{CC}=0.9 \sim 3.6\text{V}, I_{OL}=20\mu\text{A}$	--	--	0.1	V	
		$V_{CC}=1.1\text{V}, I_{OL}=1.1\text{mA}$	--	--	$0.3 \times V_{CC}$	V	
		$V_{CC}=1.4\text{V}, I_{OL}=1.7\text{mA}$	--	--	0.31	V	
		$V_{CC}=1.65\text{V}, I_{OL}=1.9\text{mA}$	--	--	0.31	V	
		$V_{CC}=2.3\text{V}$	$I_{OL}=2.3\text{mA}$	--	--	0.31	V
			$I_{OL}=3.1\text{mA}$	--	--	0.44	V
		$V_{CC}=3\text{V}$	$I_{OL}=2.7\text{mA}$	--	--	0.31	V
			$I_{OL}=4\text{mA}$	--	--	0.44	V
Input Leakage Current	$I_{I(LEAK)}$	$V_{CC}=0 \sim 3.6\text{V}, V_{IN}=\text{GND} \sim 3.6\text{V}$	--	--	± 0.1	μA	
Power OFF Leakage Current	I_{off}	$V_{CC}=0\text{V}, V_{IN}$ or $V_{OUT}=0 \sim 3.6\text{V}$	--	--	± 0.2	μA	
Additional Power OFF Leakage Current	ΔI_{off}	$V_{CC}=0\text{V} \sim 0.2\text{V}, V_{IN}$ or $V_{OUT}=0 \sim 3.6\text{V}$	--	--	± 0.2	μA	
Quiescent Supply Current	I_{CC}	$V_{CC}=0.9 \sim 3.6\text{V}, V_{IN}=V_{CC}$ or $\text{GND}, I_{OUT}=0$	--	--	0.5	μA	
Additional Quiescent Supply Current Per Input Pin	ΔI_{CC}	$V_{CC}=3.3\text{V}, V_{IN}=V_{CC}-0.6\text{V}, I_{OUT}=0$	--	--	40	μA	
Input Capacitance	CI	$V_{CC}=0\text{V} \sim 3.6\text{V}, V_{IN}=V_{CC}$ or GND	--	1.5	--	pF	
Output Capacitance	C_{OUT}	$V_{CC}=0\text{V}, V_{OUT}=\text{GND}$	--	3.0	--	pF	

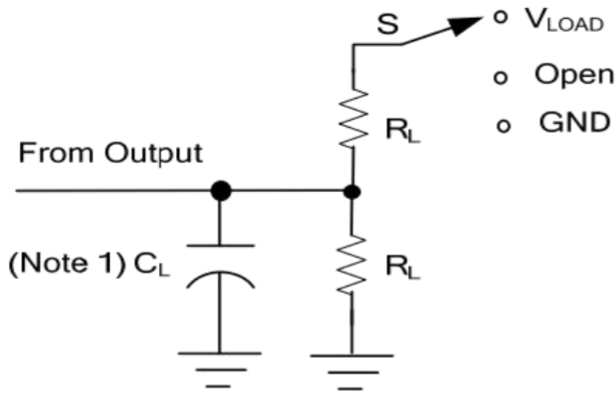
OPERATING CHARACTERISTICS (f=10MHz, TA =25°C , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	C _{PD}	V _{CC} =0.9V	--	3.8	--	pF
		V _{CC} =1.2±0.1V	--	3.7	--	pF
		V _{CC} =1.5±0.1V	--	3.7	--	pF
		V _{CC} =1.8±0.15V	--	3.7	--	pF
		V _{CC} =2.5±0.2V	--	3.9	--	pF
		V _{CC} =3.3±0.3V	--	4.0	--	pF

SWITCHING CHARACTERISTICS (TA =25°C, unless otherwise specified)

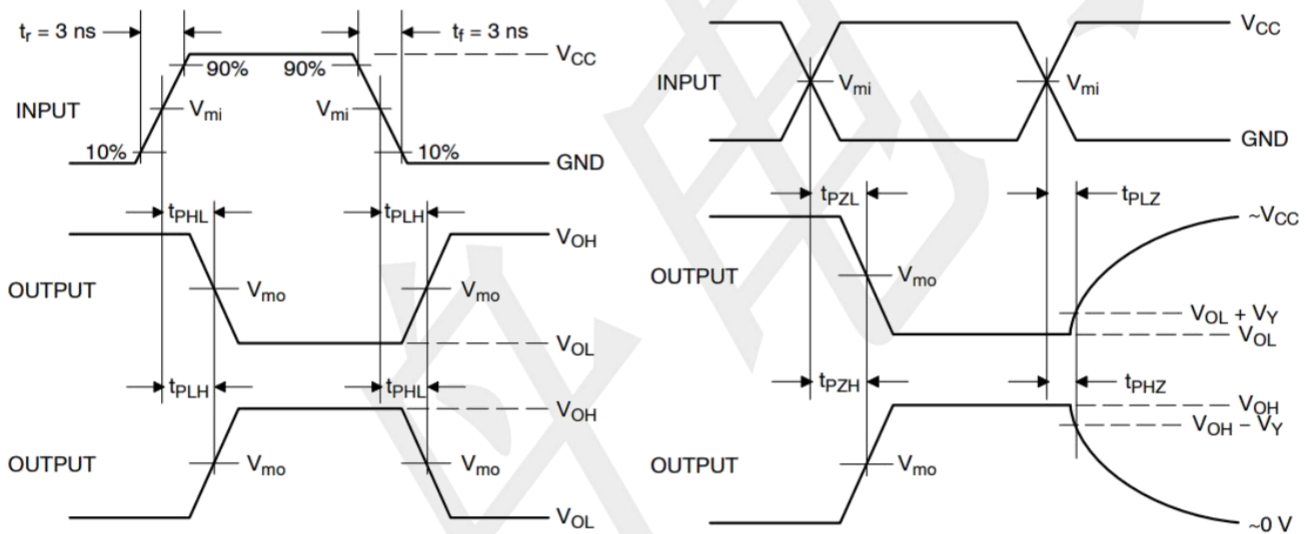
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Propagation delay from inputs (A) to output(Y)	t _{PD}	CL=5pF, RL=1MΩ	V _{CC} =0.9V	--	18.1	--	ns
			V _{CC} =1.2±0.1V	4.3	7.4	--	ns
			V _{CC} =1.5±0.1V	3.3	5.2	--	ns
			V _{CC} =1.8±0.15V	2.6	4.1	--	ns
			V _{CC} =2.5±0.2V	2	2.9	--	ns
			V _{CC} =3.3±0.3V	1.7	2.4	--	ns
		CL=10pF, RL=1MΩ	V _{CC} =0.9V	--	20.5	--	ns
			V _{CC} =1.2±0.1V	4.6	8.4	--	ns
			V _{CC} =1.5±0.1V	3.5	5.9	--	ns
			V _{CC} =1.8±0.15V	3.9	4.7	--	ns
			V _{CC} =2.5±0.2V	2.3	3.4	--	ns
			V _{CC} =3.3±0.3V	2.1	2.8	--	ns
		CL=15pF, RL=1MΩ	V _{CC} =0.9V	--	22.5	--	ns
			V _{CC} =1.2±0.1V	5.8	9.3	--	ns
			V _{CC} =1.5±0.1V	4.4	6.6	--	ns
			V _{CC} =1.8±0.15V	3.5	5.3	--	ns
			V _{CC} =2.5±0.2V	2.7	3.9	--	ns
			V _{CC} =3.3±0.3V	2.4	3.2	--	ns
		CL=30pF, RL=1MΩ	V _{CC} =0.9V	--	29	--	ns
			V _{CC} =1.2±0.1V	7.4	12	--	ns
			V _{CC} =1.5±0.1V	5.7	8.6	--	ns
			V _{CC} =1.8±0.15V	4.8	6.9	--	ns
			V _{CC} =2.5±0.2V	3.9	5.1	--	ns
			V _{CC} =3.3±0.3V	3.5	4.8	--	ns

TEST CIRCUIT AND WAVEFORMS



TEST	S
t_{PLH}/t_{PHL}	Open
t_{PHZ}/t_{PZH}	GND
t_{PLZ}/t_{PZL}	$2 \times V_{CC}$

TEST CIRCUIT



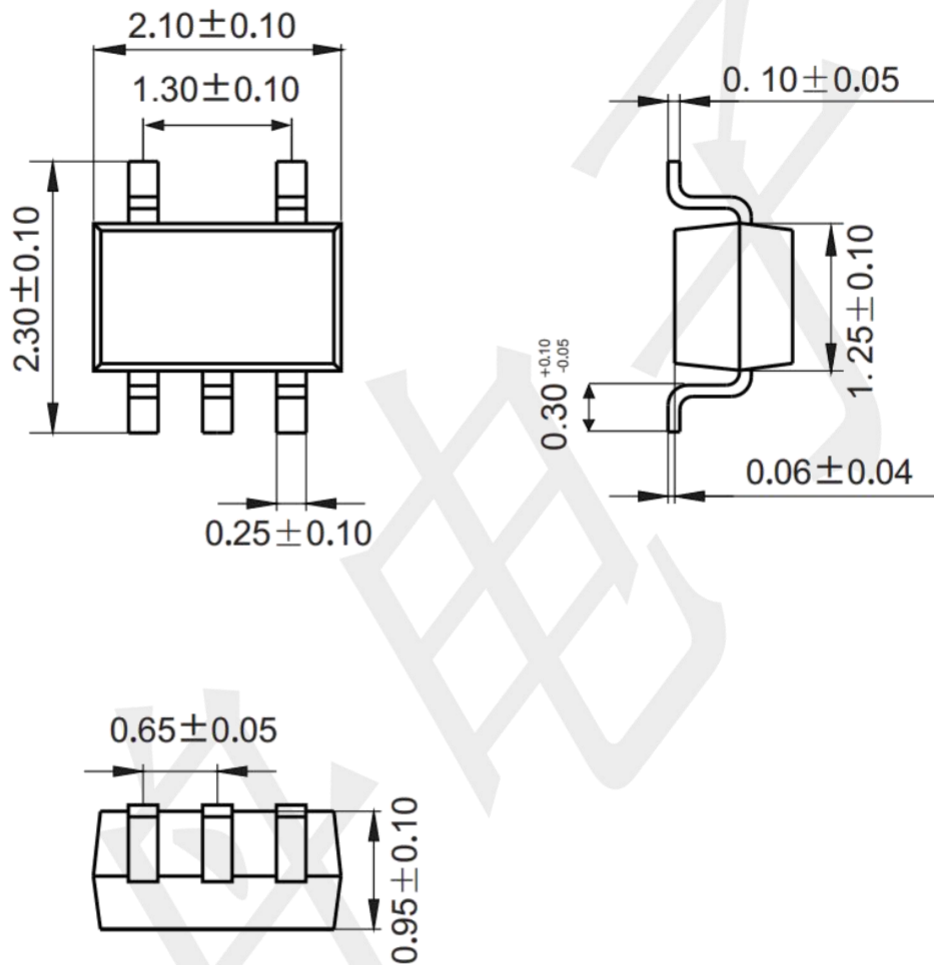
V_{CC}, V	V_{mi}, V	V_{mo}, V		V_Y, V
		t_{PLH}, t_{PHL}	$t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}$	
0.9	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	0.1
1.1 to 1.3	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	0.1
1.4 to 1.6	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	0.1
1.65 to 1.95	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	0.15
2.3 to 2.7	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	0.15
3.0 to 3.6	1.5	1.5	1.5	0.3

Notes:

1. C_L includes probe and jig capacitance.
2. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O = 50 \Omega$.

Package information (Unit: mm)

SOT353



Mounting Pad Layout (unit: mm)

